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Kind regards,

Team Nexperia

PMEG1020EA

2 A ultra low V_F MEGA Schottky barrier rectifier Rev. 04 — 30 December 2008 Pro

Product data sheet

Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in SOD323 (SC-76) very small Surface-Mounted Device (SMD) plastic package.

1.2 Features

- Forward current: I_F ≤ 2 A
- Reverse voltage: V_R ≤ 10 V
- Ultra low forward voltage
- Very small SMD plastic package

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current	$T_{sp} \le 55 ^{\circ}C$	-	-	2	Α
V_R	reverse voltage		-	-	10	V
V _F	forward voltage	I _F = 1 A	[1] _	280	350	mV

[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$



Pinning information 2.

Table 2. **Pinning**

Description	Simplified outline	Graphic symbol
cathode	[1]	
anode	1 2	1 - 2
		sym001
	Description cathode	cathode [1]

^[1] The marking bar indicates the cathode.

Ordering information 3.

Table 3. **Ordering information**

Type number	Package				
	Name	Description	Version		
PMEG1020EA	SC-76	plastic surface-mounted package; 2 leads	SOD323		

Marking

Table 4. **Marking codes**

Type number	Marking code
PMEG1020EA	E2

Limiting values

Table 5. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_R	reverse voltage		-	10	V
I _F	forward current	T _{sp} ≤ 55 °C	-	2	Α
I _{FRM}	repetitive peak forward current	$t_p \leq 1 \text{ ms; } \delta \leq 0.5$	-	3.2	Α
I _{FSM}	non-repetitive peak forward current	square wave; t _p = 8 ms	-	9	Α
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

2 of 9

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Tvp	Max	Unit	
Syllibol	raiailletei	Conditions	IVIIII	ıур	IVIAX	Offic	
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u> _	-	450	K/W	
			[2] _	-	210	K/W	
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[3] _	-	90	K/W	

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 7. Characteristics

T_{amb} = 25 °C unless otherwise specified.

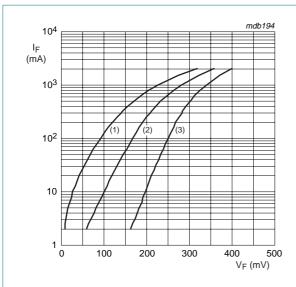
	_					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage		<u>[1]</u>			
		$I_F = 0.01 A$	-	100	130	mV
		$I_F = 0.1 A$	-	170	200	mV
		I _F = 1 A	-	280	350	mV
		I _F = 2 A	-	350	460	mV
I _R	reverse current		[2]			
		$V_R = 5 V$	-	0.7	2	mA
		V _R = 8 V	-	1	2.5	mA
		V _R = 10 V	-	1.2	3	mA
C _d	diode capacitance	$V_R = 5 V$; $f = 1 MHz$	-	37	45	pF

^[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02.$

^[2] Device mounted on an FR4 PCB with copper clad 10×10 mm.

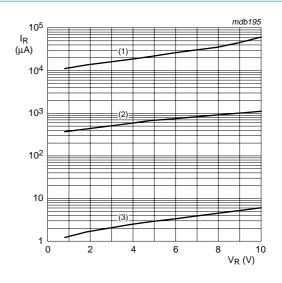
^[3] Soldering point of cathode tab.

^[2] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.



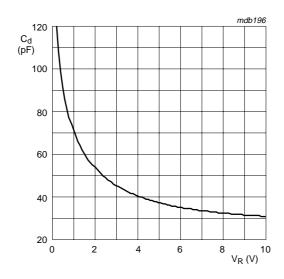
- (1) $T_{amb} = 85 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

Forward current as a function of forward Fig 1. voltage; typical values



- (1) $T_{amb} = 85 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

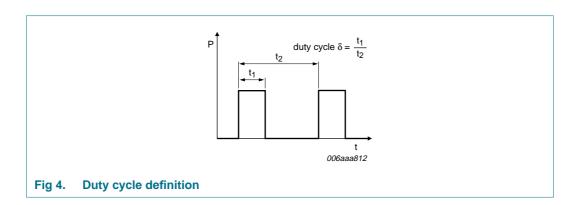
Fig 2. Reverse current as a function of reverse voltage; typical values



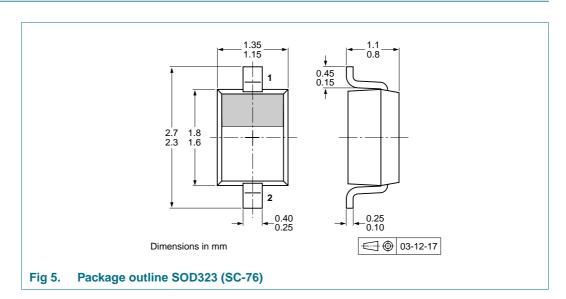
 $f = 1 \text{ MHz}; T_{amb} = 25 ^{\circ}\text{C}$

Fig 3. Diode capacitance as a function of reverse voltage; typical values

8. Test information



9. Package outline



10. Packing information

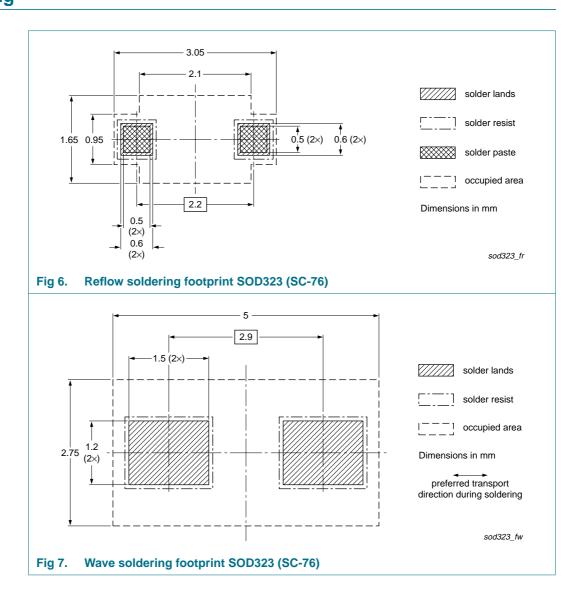
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	
			3000	10000
PMEG1020EA	SOD323	4 mm pitch, 8 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see $\underline{\text{Section 14}}$.

11. Soldering



12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG1020EA_4	20081230	Product data sheet	-	PMEG1020EA_3
Modifications:	guidelines	t of this data sheet has been re of NXP Semiconductors. s have been adapted to the new		•
	· ·	·	v company name whe	ете арргорпате.
	Section 13	"Legal information": updated		
PMEG1020EA_3	20040206	Product specification	-	PMEG1020EA_2
PMEG1020EA_2	20030715	Product specification	-	PMEG1020EA_1
PMEG1020EA_1	20030307	Preliminary specification	-	-

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PMEG1020EA

2 A ultra low V_F MEGA Schottky barrier rectifier

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